TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHCT138AF, TC74VHCT138AFN, TC74VHCT138AFT

3-TO-8 LINE DECODER

The TC74VHCT138 is an advanced high speed CMOS 3-TO-8 LINE DECODER fabricated with silicon gate C2MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs $(\overline{Y}0 - \overline{Y}7)$ will go low. When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high. G1, G2A, and G2B inputs are provided to ease cascade connection and for use as an address decoder for memory

The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing 3.3V to 5V system.

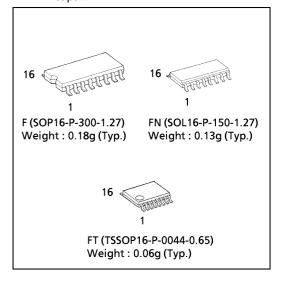
Input protection and output circuit ensure that 0 to 5.5V can be applied to the input and output*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

 $*1:V_{CC}=0V$

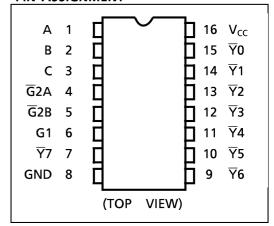
FEATURES:

- High Speed······ t_{pd} = 7.6ns(typ.) at V_{CC} = 5V
- Compatible with TTL outputs $\cdots V_{IL} = 0.8V$ (Max.) $V_{IH} = 2.0V (Min.)$
- Power Down Protection is provided on all inputs and
- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with the 74 series (74AC/HC /F/ALS/LS etc.) 138 type.

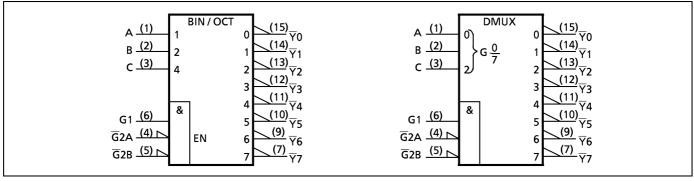
(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT



IEC LOGIC SYMBOL



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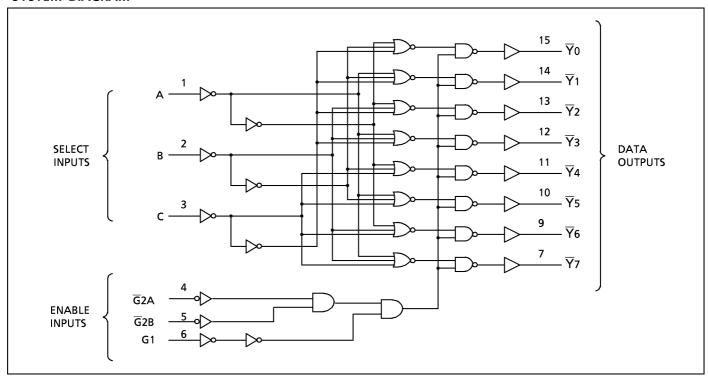
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TRUTH TABLE

	INPUTS													
ENABLE			SELECT		_{₹0}	<u></u> 71			<u></u>		<u></u> <u></u> <u></u> <u></u> <u></u> <u></u> <u></u> <u></u> <u></u>	<u>7</u> 7	SELECTED OUTPUT	
G1	G2A	G ₂ B	С	В	Α	10	' '	12	13	14	13	-	' /	
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	NONE
Х	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	NONE
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	NONE
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	<u>\(\bar{Y}\) 0 \\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ </u>
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	<u>\(\bar{Y} \) 1</u>
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	\overline{Y} 2
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	<u>\(\bar{Y} \) 3</u>
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	<u>¥</u> 4
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	<u> </u>
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	<u> </u>
Н	L	L	Н	Н	Ι	Н	Н	Н	Н	Н	Н	Η	L	\ \ \overline{Y}7

X: Don't Care

SYSTEM DIAGRAM



000707EBA2'

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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V _{CC}	− 0.5~7.0	V
DC Input Voltage	V _{IN}	− 0.5~7.0	V
DC Output Voltage	V _{OUT}	−0.5~7.0 (Note 1)	V
De Output Voltage	VOUT	$-0.5 \sim V_{CC} + 0.5$ (Note 2)	v
Input Diode Current	I _{IK}	-20	mΑ
Output Diode Current	I _{OK}	± 20 (Note 3)	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} /Ground Current	I _{cc}	± 75	mΑ
Power Dissipation	P _D	180	mW
Storage Temperature	T _{stg}	−65~150	°C

(Note 1) $V_{CC} = 0V$

(Note 2) High or Low State. $I_{\mbox{\scriptsize OUT}}$ absolute maximum rating must be observed.

(Note 3) V_{OUT} <GND, V_{OUT} > V_{CC}

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT						
Supply Voltage	V _{cc}	4.5~5.5	٧						
Input Voltage	VIN	0~5.5	V						
Output Voltage	V _{OUT}	0~5.5 (Note 4)	V						
Output voltage	VOUT	0~V _{CC} (Note 5)							
Operating Temperature	Topr	−40~85	°C						
Input Rise and Fall Time	dt/dV	0~20	ns / V						

(Note 4) $V_{CC} = 0V$

(Note 5) High or Low State.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMPOL	CONI			Ta = 25°C		Ta = -4	UNIT		
PARAIVIETER	SYMBOL	CONL	V _{cc} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNII	
High - Level Input Voltage	VIH		4.5~5.5	2.0		_	2.0	_	>	
Low - Level Input Voltage	VIL			4.5~5.5	1		0.8	_	0.8	>
High - Level	Vон	V _{I N} =	$I_{OH} = -50\mu A$	4.5	4.40	4.50	_	4.40		V
Output Voltage	∨ он	VIH or VIL	I _{OH} = -8mA	4.5	3.94	_	_	3.80	_	
Low - Level	Vol	V _{I N} =	$I_{OL} = 50 \mu A$	4.5	_	0.0	0.1	_	0.1	>
Output Voltage	VOL	V _{IH} or V _{IL}	I _{OL} = 8mA	4.5	_	_	0.36	_	0.44	V
Input Leakage Current	I _{I N}	$V_{1N} = 5.5V$ or	V _{IN} = 5.5V or GND			_	± 0.1	_	± 1.0	μΑ
	I _{cc}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	_	40.0	7
Quiescent Supply Current	I _{CCT}	PER INPUT :	5.5			1.35	_	1.50	mA	
Output Leakage Current	I _{OPD}	V _{OUT} = 5.5V		0	_	_	0.5	_	5.0	μΑ

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION				Ta = 25°C		Ta = -4	UNIT	
PANAMETER	3 TIVIBOL		V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	ONIT
Propagation Delay Time $(A, B, C - \overline{Y})$	t_pLH		5.0 ± 0.5	15	_	7.6	10.4	1.0	12.0	ns
(A,B,C-Y)	t_pHL			50	_	8.1	11.4	1.0	13.0	
Propagation Delay Time $(G1 - \overline{Y})$	t _{pLH} t _{pHL}		5.0 ± 0.5	15	_	6.6	9.1	1.0	10.5	
(G1 – ₹)				50	_	7.1	10.1	1.0	11.5	
Propagation Delay Time	t _{pLH}		5.0 ± 0.5	15	_	7.0	9.6	1.0	11.0	
$(\overline{G}2 - \overline{Y})$	t_pHL			50	_	7.5	10.6	1.0	12.0	MHz
Input Capacitance	C _{IN}				_	4	10	_	10	2
Power Dissipation Capacitance	C_PD		(Note 1)		_	49	_	_	_	pF

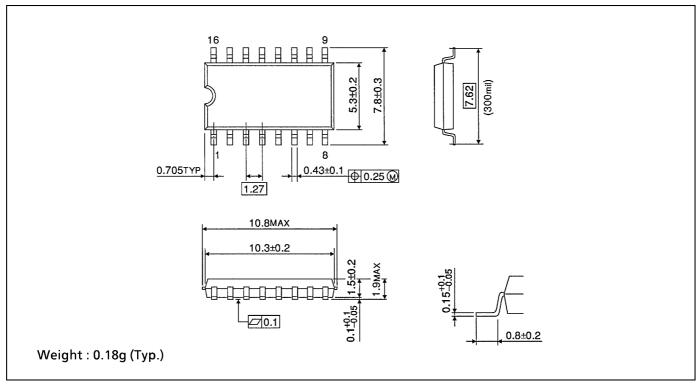
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

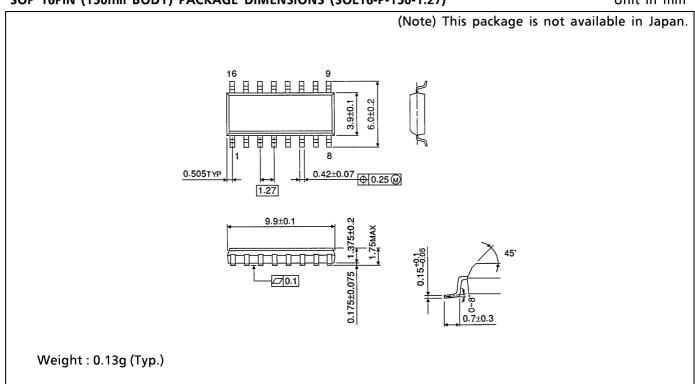
SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150-1.27)

Unit in mm



TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65)

Unit in mm

